

2MBI600VE-060-50

IGBT Modules

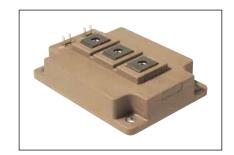
IGBT MODULE (V series) 600V / 600A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

■ Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items		Symbols	Conditions	'	Maximum ratings	Units	
Collector-Emitte	r voltage	Vces				V	
Gate-Emitter voltage		V _{GES}			±20	V	
	ent	Ic	Continuous	Tc=80°C	600		
ž			Continuous	Tc=25°C	780		
≥ Collector current		I _{c pulse}	1ms	,	1200	V	
드		-I _c			600		
		-Ic pulse	1ms		1200		
Collector power dissipation		Pc	1 device		2940	W	
Junction temperature		Tj			175	°C	
Operating junction temperature (under switching conditions)		Tjop		,	150		
Case temperature		Tc			125		
Storage temperature		T _{stg}			-40 ~ +125		
Isolation voltage between terminal and copper base (*1)		Viso	AC: 1min.	AC : 1min.		VAC	
Sorous torque	ounting (*2)				6.0	N m	
Screw torque	erminals (*3)]-			5.0	IN III	

Note *1: All terminals should be connected together during the test. Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at T_i= 25°C unless otherwise specified)

	Cumbala	mb ala Canditiana			Characteristics		Halta
ems	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 600V		-	-	2.0	mA
Gate-Emitter leakage current I_{GES} $V_{CE} = 0V$, $V_{GE} = \pm 20V$			-	-	800	nA	
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 600mA		6.2	6.7	7.2	V
	V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 600A	T _j =25°C	-	1.85	2.40	V
			T _j =125°C	-	2.15	-	
Collector-Emitter saturation voltage			T _j =150°C	-	2.35	-	
Conector-Emitter Saturation Voltage	V _{CE (sat)} (chip)		T _j =25°C	-	1.60	1.85	
			T _j =125°C	-	1.90	-	
			T _j =150°C	-	2.10	-	
Internal gate resistance	R _{g(int)}	-		-	1.5	-	Ω
Input capacitance Turn-on time	Cies	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$		-	38.8	-	nF
	ton			-	0.75	-	µsec
Turn-on time	t _r	Vcc = 300V, Ic = 600A	-	0.40	-		
	t _{r (i)}	$V_{GE} = \pm 15V$, $R_G = 2.2\Omega$ $T_J = 150$ °C, $L_S = 30$ nH		-	0.15	-	
Turn-off time	toff			-	0.75	-	
Turn-on time	t _f			-	0.07	-	
	VF	V _{GE} = 0V I _F = 600A	T _j =25°C	-	1.75	2.35	V
	(terminal)		T _j =125°C	-	1.65	-	
Forward on voltage	(terminar)		T _j =150°C	-	1.62	-	
Forward on voilage	V _F (chip)		T _j =25°C	-	1.60	1.85	
			T _j =125°C	-	1.50	-	
			T _j =150°C	-	1.47	-	
Reverse recovery time trr I _F = 600A			-	0.25	-	μsec	

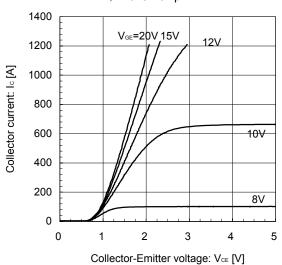
■ Thermal resistance characteristics

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Items	Symbols	Conditions	Characteristics			Units		
items		Conditions	min.	typ.	max.	Units		
Thermal registance (1device)	Ь	IGBT	-	-	0.051	°C/W		
Thermal resistance (1device)	R _{th(j-c)}	FWD	-	-	0.088			
Contact thermal resistance (1device) (*4)	R _{th(c-f)}	with Thermal Compound	-	0.0125	-			

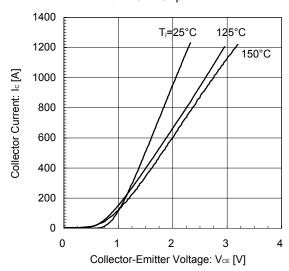
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

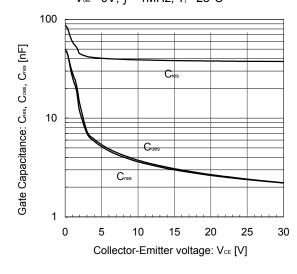
Collector current vs. Collector-Emitter voltage (typ.) T_i = 25°C / chip



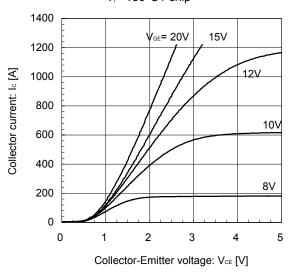
Collector current vs. Collector-Emitter voltage (typ.) $V_{GE} = 15V / chip$



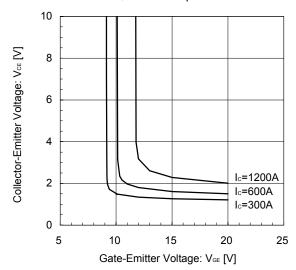
Gate Capacitance vs. Collector-Emitter Voltage V_{GE} = 0V, f = 1MHz, T_{J} = 25°C



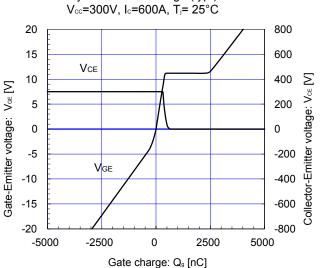
Collector current vs. Collector-Emitter voltage (typ.) T_,= 150°C / chip

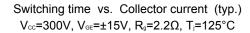


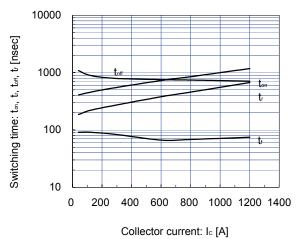
Collector-Emitter voltage vs. Gate-Emitter voltage T_i= 25°C / chip



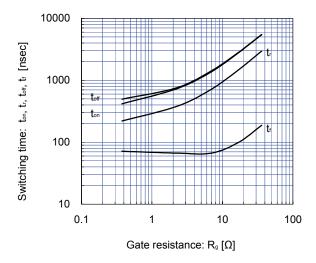
Dynamic Gate Charge (typ.)



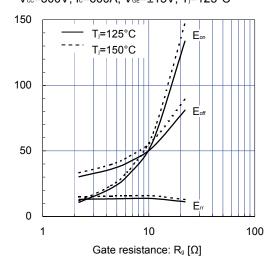




Switching time vs. Gate resistance (typ.) $V_{cc}=300V$, $I_c=600A$, $V_{cE}=\pm15V$, $T_i=125^{\circ}C$

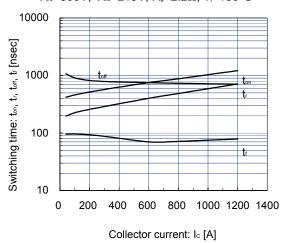


Switching loss vs. Gate resistance (typ.) V_{cc} =300V, I_{c} =600A, V_{GE} =±15V, T_{j} =125°C

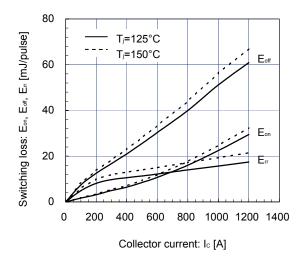


Switching loss: Eon, Eoff, Err [mJ/pulse]

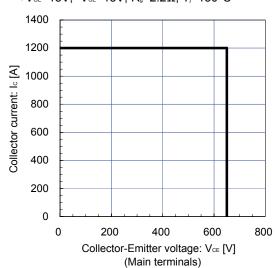
Switching time vs. Collector current (typ.) $V_{\text{CC}}{=}300V,\,V_{\text{GE}}{=}{\pm}15V,\,R_{\text{g}}{=}2.2\Omega,\,T_{\text{j}}{=}150^{\circ}C$

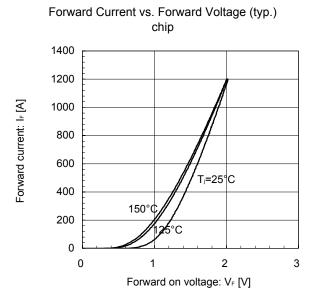


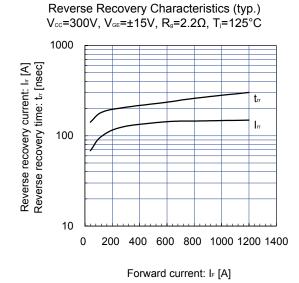
Switching loss vs. Collector current (typ.) V_{CC} =300, V_{GE} =±15V, R_{g} =2.2 Ω , T_{j} =125°C

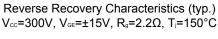


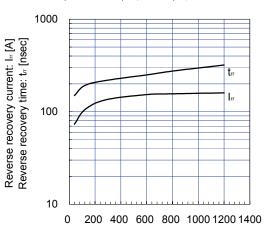
Reverse bias safe operating area (max.) $+V_{\text{GE}}=15V$, $-V_{\text{GE}}=15V$, $R_{\text{g}}=2.2\Omega$, $T_{\text{j}}=150^{\circ}\text{C}$



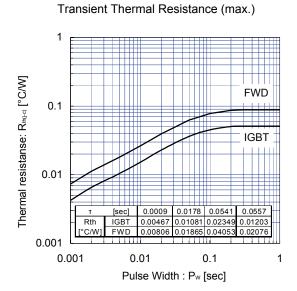






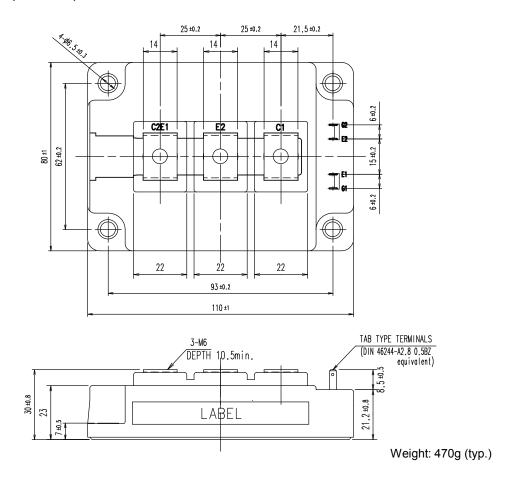


Forward current: IF [A]

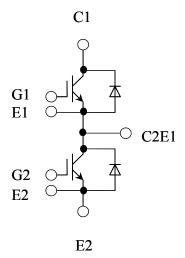


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■ Outline Drawings (Unit: mm)



■ Equivalent Circuit



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